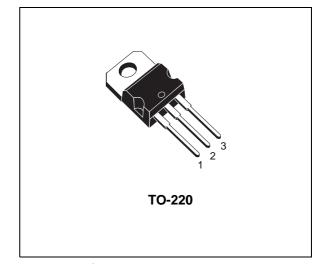


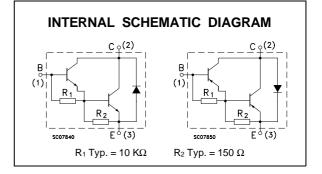
BDX33B BDX33C BDX34B BDX34C

COMPLEMENTARY SILICON POWER DARLINGTON TRANSISTORS

DESCRIPTION

The BDX33B and BDX33C are silicon Epitaxial-Base NPN power transistors in monolithic Darlington configuration mounted in Jedec TO-220 plastic package. They are intented for use in power linear and switching applications. The complementary PNP types are BDX34B and BDX34C respectively.





ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter			Unit	
		NPN	BDX33B	BDX33C	
		PNP	BDX34B	BDX34C	
V _{CBO}	Collector-Base Voltage (I _E = 0)		80	100	V
V_{CEO}	Collector-Emitter Voltage $(I_B = 0)$		80	100	V
Ιc	Collector Current		10		Α
I _{CM}	Collector Peak Current		15		А
Ι _Β	Base Current		0.25		Α
P _{tot}	Total Dissipation at $T_c \le 25$ °C		70		W
T _{stg}	Storage Temperature		-65 to 150		°C
Tj	Max. Operating Junction Temperature	150		°C	

For PNP types voltage and current values are negative.

October 1999

THERMAL DATA

Rthj-case Thermal Resistance Junction-case 1.78 °C/V	R _{thj-case}	Thermal Resistance Junction-case	1.78	°C/W
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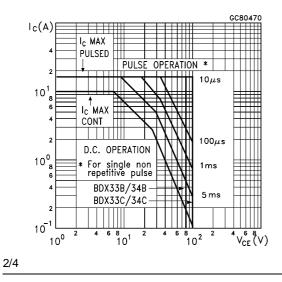
ELECTRICAL CHARACTERISTICS (T_{case} = 25 °C unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector Cut-off Current (I _E = 0)	for BDX33B/34B $V_{CB} = 80 V$ for BDX33C/34C $V_{CB} = 100V$ $T_{case} = 100 °C$			0.2 0.2	mA mA
		for BDX33B/34B $V_{CB} = 80 V$ for BDX33C/34C $V_{CB} = 100 V$			5 5	mA mA
Iceo	Collector Cut-off Current $(I_B = 0)$				0.5 0.5 10 10	mA mA mA mA
I _{EBO}	Emitter Cut-off Current $(I_{C} = 0)$	V _{EB} = 5 V			5	mA
$V_{CEO(sus)^*}$	Collector-Emitter Sustaining Voltage $(I_B = 0)$	I _C =100 mA for BDX33B/34B for BDX33C/34C	80 100			V V
$V_{CER(sus)^*}$	Collector-emitter Sustaining Voltage (R_{BE} =100 Ω)	I _C = 100 mA for BDX33B/34B for BDX33C/34C	80 100			V V
$V_{CEV(sus)^*}$	Collector-emitter Sustaining Voltage (V _{BE} =-1.5 V)	I _C = 100 mA for BDX33B/34B for BDX33C/34C	80 100			V V
V _{CE(sat)} *	Collector-emitter Saturation Voltage	$I_{\rm C} = 3 \text{ A}$ $I_{\rm B} = 6 \text{ mA}$			2.5	V
$V_{BE}*$	Base-emitter Voltage	I _C = 3 A V _{CE} = 3 V			2.5	V
h _{FE} *	DC Current Gain	I _C = 3 A V _{CE} = 3 V	750			V
V_{F}^{*}	Parallel-Diode Forward Voltage	I _F = 8 A			4	V
h _{fe}	Small Signal Current Gain	$I_C = 1 \text{ A } V_{CE} = 5 \text{ V } f = 1 \text{MHz}$	100			

* Pulsed: Pulse duration = 300 μ s, duty cycle 1.5 %

For PNP types voltage and current values are negative.

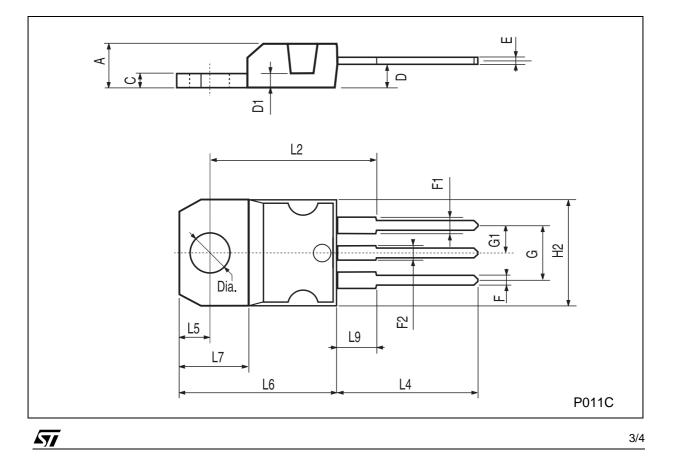
Safe Operating Area



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DIM.		mm			inch	
Diwi.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А	4.40		4.60	0.173		0.181
С	1.23		1.32	0.048		0.051
D	2.40		2.72	0.094		0.107
D1		1.27			0.050	
E	0.49		0.70	0.019		0.027
F	0.61		0.88	0.024		0.034
F1	1.14		1.70	0.044		0.067
F2	1.14		1.70	0.044		0.067
G	4.95		5.15	0.194		0.203
G1	2.4		2.7	0.094		0.106
H2	10.0		10.40	0.393		0.409
L2		16.4			0.645	
L4	13.0		14.0	0.511		0.551
L5	2.65		2.95	0.104		0.116
L6	15.25		15.75	0.600		0.620
L7	6.2		6.6	0.244		0.260
L9	3.5		3.93	0.137		0.154
DIA.	3.75		3.85	0.147		0.151

TO-220 MECHANICAL DATA



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